# The LHCb VELO Upgrade

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Conclusions

## Outline

## LHCb experiment

Current detector

#### Upgrade LHCb upgrade VELO upgrade

Test beam TPx3 telescope and results

#### Conclusions

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# The LHCb experiment

LHCb is a forward spectrometer designed to study flavor physics exploiting the enormous production cross sections of heavy hadrons at the LHC



#### Characteristics

- Built for  $\mathcal{L} = 2 \times 10^{32} \mathrm{cm}^{-2} \mathrm{s}^{-1}$  at 25 ns spacing, with an average of  $\mu = 0.4$  interactions per bunch crossing
- In 2012 it ran at a  $\mathcal{L} = 4 \times 10^{32} \text{cm}^{-2} \text{s}^{-1}$  at 50 ns spacing with  $\mu = 1.4$
- Has recorded 1.1  $fb^{-1}$  in 2011 and 2  $fb^{-1}$  in 2012

#### Efficiencies

- All detectors with  $>\sim$  99% active channels
- $\epsilon$ (operation)>94%
- ∼98% are good data

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## LHCb upgrade



- Remove Hardware trigger. Use software-only trigger
- 1 to 30 MHz trigger rate
- Output rate from 12.5 to 100 kHz
- Increase luminosity to  $\geq 2 \times 10^{33} \text{ cm}^{-2} \text{s}^{-1}$
- We aim to record 10 fb<sup>-1</sup> per year

Apart from the increase in luminosity and trigger rate, we expect an increment of a factor 10 and 20 in the muonic and hadronic channels yield respectively

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## **Detectors upgrade**



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## **VELO upgrade**

### Requirements and challenges

- Data-driven readout at 40 MHz  $\Rightarrow$  up to 2.85 Tbit/s from whole VELO
- Radiation hardness at  $8\times 10^{15}$  1 MeV  $_{neq}$  cm<sup>2</sup>. Highly non-uniform radiation:  $5.2\times r^{-1.9}$  hits event  $^{-1}cm^{-2}$
- Keep/improve performance
- Increase granularity to allow operation at  $\mathcal{L} \ge 2 \times 10^{33} \text{cm}^{-2} \text{s}^{-1}$
- Minimise material in acceptance
- Provide fast and robust track reconstruction (essential for software trigger)



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## **VELO upgrade**

#### Characteristics of the new VELO

- · From micro-strips to pixels
- Full detector consists of 26 stations (1 station = 2 modules, one on either side of the beam)
- Closest pixel is at 5.1 mm from the beam centre
- Separated from the beam vacuum by a 250  $\mu$ m RF foil
- Geometrical efficiency > 99 % for R < 10 mm
- Track rate (and radiation damage) will be 10x higher





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## Modules



- 4 sensor tiles (14x42 mm<sup>2</sup>), 2 on each side of substrate
- Each tile is bump bonded to 3 ASIC for readout
- Silicon substrate with integrated micro-channels for cooling
- Material in active region  ${\sim}0.9\%~X_0$

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## ASIC

#### Velopix

The upgraded VELO will be based on Velopix ASIC (successor of Timepix3) 55  $\mu$ m x 55  $\mu$ m pixel size, 256 x 256 matrix

- · Binary readout
- Hit rate up to 900 MHits/s. (Above 15.1 Gbit/s)
- Data driven readout: each hit is time-stamped, labeled and sent off chip immediately in a superpixel structure
- Radiation hard up to 400 MRad
- Submission planned for 2015 Q4







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## Silicon sensors

- Planar silicon n-in-p (evaluating n-in-n)
- Tile for 3 VeloPix chips:  $\sim$ 43 mm  $\times$  14 mm, thickness 200  $\mu$ m
- 55  $\mu$ m  $\times$  55  $\mu$ m pixel size
- 110 μm gap between ASICs bridged by elongated pixel implants
- Non homogeneous irradiation sets constraints on guard ring design
  - $\rightarrow$  factor  $\sim$ 140 difference in fluence from tip to far corner
  - $\rightarrow$  bias voltage at end on life  $\sim$ 1000 Volts for tip
  - $\rightarrow~$  guard ring width  ${\sim}450~\mu{\rm m}$



Sensor tile on a hybrid board





Hamamatsu prototype sensor

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# Cooling

- High speed pixel readout chips produce a lot of heat (~1.5 W/cm<sup>2</sup>)
- Keep the sensors at < -20°C to minimize the effects of radiation damage, and to avoid thermal runaway
- Novel method: evaporate CO2 via micro-channels etched in Si substrate
- Bring the cooling power where you need it, using least material
- No CTE difference (Si on Si)



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## **RF** foil

#### The RF foil is a de facto beam pipe

#### Severe requirements:

- Vacuum tight ( $< 10^{-9}$  mbar l/s)
- Radiation hard
- Low mass but mechanically stable
- Good electrical conductivity to mirror beam currents and shield against RF noise pick-up in FE electronics
- Thermally stable and conductive (heat load from the beam)





Sample with central part thinned to 150  $\mu$ m

### Material and fabrication:



- Mill foil from solid Al alloy block
- Achieve 250  $\mu$ m thickness
- Chemical thinning being investigated to reduce the central part

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## Test beam

#### TimePix3 telescope

- 8 planes divided in two arms
- Each plane consist in a Timepix3 chip bump bonded to a 300  $\mu$ m p-on-n Si sensor
- Track rate > 5 MHz. Only limited by beam intensity
- Resolution at the DUT plane 2  $\mu$ m (with 180 GeV/c  $\pi$  beam)
- $1.4 \times 1.4 \text{ cm}^2$  of active area
- Data driven readout



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## **Test beam**

## 200 $\mu m$ thick Hamamatsu 3×1 tile on 3 Timepix3 chips bump-bonded by Advacam



Hit map of a  $3 \times 1$  tile in a 180 GeV SPS beam

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## **Test beam**

#### 200 $\mu$ m n-on-p sensor from Micron. Bias = -200 V. Non irradiated



Interpixel fractions from left to right 66 %, 30 %, 2.5 %, 1.5 %

200  $\mu$ m n-on-p sensor from HPK. Bias = -300 V. Irradiated to 4  $\times$  10<sup>15</sup> 1 MeV n<sub>eq</sub> cm<sup>2</sup>



Interpixel fractions from left to right 93 %, 6 %, 0.8 %, 0.2 %

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## Conclusions

The requirements for the LHCb VELO upgrade are very demanding:

- Luminosity will be increased by a factor  $\geq 5$
- · Keep or improve the performance of the current VELO

Upgrade VELO characteristics:

- Vertex Locator will consist of planar silicon pixels, 55 x 55  $\mu$ m<sup>2</sup>
- The first pixel will be only at 5.1 mm from the beam axis
- Evaporative CO2 cooling in Silicon micro-channel substrate
- Material budget reduction in elements placed in the acceptance (modules, RF-Foil)

Still a lot of work to do:

- Intense testbeam program to validate: sensor technologies, radiation hardness, cooling schemes and readout electronics
- · Sensor, electronics, modules and mechanics production

#### Installation during long shutdown 2 in 2019

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# Backup

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## **The Vertex Locator (VELO)**

- Silicon strip detector surrounding the interaction point
- 88 silicon n<sup>+</sup>-on-n sensors, 300  $\mu$ m thick, R- $\phi$  design
- · Located only 8 mm from the beams
- Enclosed into a separated vacuum box (RF Foil)
- · Halves are separated for beams injection
- 1 MHz trigger rate
- Bi-phase CO<sub>2</sub> cooling system







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#### Comparison between current and upgraded VELO

- A smaller RF foil inner radius (3.5 versus 5.5 mm)
- A smaller inner edge distance to the beams for the sensitive part; R<sub>det</sub> ~ 5.1 mm versus 8 mm
- A coarser inner pitch (p = 55  $\mu$ m pixels versus 40  $\mu$ m strips)
- A smaller Si thickness ( $t_{det} + t_{ASIC} = 0.4$  versus  $t_{det} = 0.6$  mm for an R-*phi* station)
- A smaller z distance between stations ( $\Delta z = 25$  versus 30 mm)



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#### Expected performance (IP resolution)



Impact parameter resolution in x for the upgrade VELO for the nominal RF foil thickness (0.25 mm) and three additional thicknesses.

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#### Expected performance ( $\tau$ and z resolutions)



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Expected performance (IP resolution with respect to fluence)

